# NSN 5962-01-177-1372

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# Body Length:

1.290 inches

# Body Width:

Between 0.500 inches and 0.610 inches

# **Body Height:**

0.210 inches

# **Maximum Power Dissipation Rating:**

1.4 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

Radar system an/fps-117

#### **Features Provided:**

Bipolar and programmable and schottky and monolithic

#### Inclosure Material:

Ceramic

### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

### Input Circuit Pattern:

14 input

# Case Outline Source And Designator:

D-3 mil-m-38510

# **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

# **Time Rating Per Chacteristic:**

125.00 nanoseconds propagation delay time, low to high level output and 125.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

#### **Test Data Document:**

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Terminal Type And Quantity:

24 printed circuit

### Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

Fiig:

A458a0

